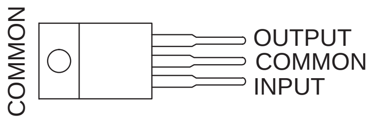
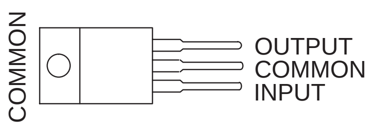
The μA78M15 is obsolete and no longer is supplied.

- **3-Terminal Regulators**
- **Output Current Up To 500 mA**
- **No External Components**
- **Internal Thermal-Overload Protection**
- **High Power-Dissipation Capability**
- **Internal Short-Circuit Current Limiting**
- **Output Transistor Safe-Area Compensation**

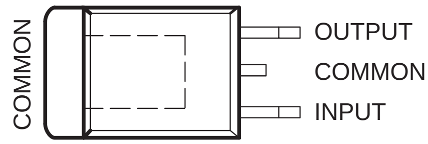
KC (TO-220) PACKAGE
(TOP VIEW)



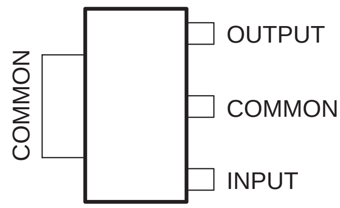
KCS (TO-220) PACKAGE
(TOP VIEW)



KTP PACKAGE
(TOP VIEW)



DCY (SOT-223) PACKAGE
(TOP VIEW)



description/ordering information

This series of fixed-voltage integrated-circuit voltage regulators is designed for a wide range of applications. These applications include on-card regulation for elimination of noise and distribution problems associated with single-point regulation. Each of these regulators can deliver up to 500 mA of output current. The internal current-limiting and thermal-shutdown features of these regulators essentially make them immune to overload. In addition to use as fixed-voltage regulators, these devices can be used with external components to obtain adjustable output voltages and currents and also as the power-pass element in precision regulators.

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

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The μA78M15 is obsolete and no longer is supplied.

description/ordering information (continued)

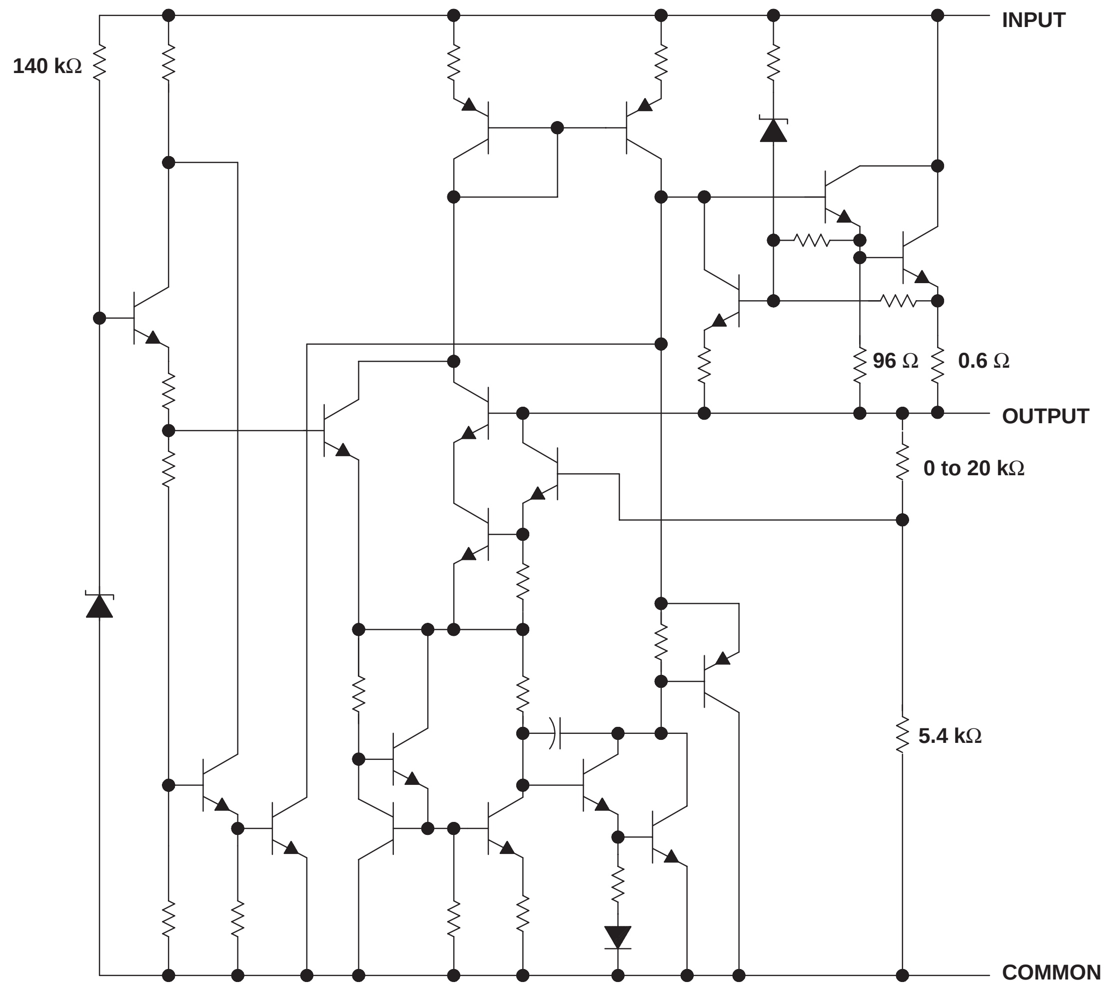
ORDERING INFORMATION

T_J	V_O(NOM) (V)	PACKAGE†		ORDERABLE PART NUMBER	TOP-SIDE MARKING
0°C to 125°C	3.3	Power Flex (KTP)	Reel of 3000	μA78M33CKTPR	UA78M33C
		SOT-223 (DCY)	Tube of 80	μA78M33CDCY	C3
			Reel of 2500	μA78M33CDCYR	
		TO-220 (KC)	Tube of 50	μA78M33CKC	UA78M33C
	5	Power Flex (KTP)	Reel of 3000	μA78M05CKTPR	UA78M05C
		SOT-223 (DCY)	Tube of 80	μA78M05CDCY	C5
			Reel of 2500	μA78M05CDCYR	
		TO-220 (KC)	Tube of 50	μA78M05CKC	UA78M05C
		TO-220, short shoulder (KCS)	Tube of 20	μA78M05CKCS	
	6	Power Flex (KTP)	Reel of 3000	μA78M06CKTPR	UA78M06C
	8	Power Flex (KTP)	Reel of 3000	μA78M08CKTPR	UA78M08C
		SOT-223 (DCY)	Tube of 80	μA78M08CDCY	C8
			Reel of 2500	μA78M08CDCYR	
		TO-220 (KC)	Tube of 50	μA78M08CKC	UA78M08C
	9	Power Flex (KTP)	Reel of 3000	μA78M09CKTPR	UA78M09C
	10	Power Flex (KTP)	Reel of 3000	μA78M10CKTPR	UA78M10C
	12	Power Flex (KTP)	Reel of 3000	μA78M12CKTPR	UA78M12C
		TO-220 (KC)	Tube of 50	μA78M12CKC	UA78M12C

† Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

The μA78M15 is obsolete and no longer is supplied.

schematic



Resistor values shown are nominal.

The μA78M15 is obsolete and no longer is supplied.

absolute maximum ratings over virtual junction temperature range (unless otherwise noted)†

Input voltage, V_I . . . . 35 V
Operating virtual junction temperature, T_J . . . . 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds . . . . 260°C
Storage temperature range, T_{stg} . . . . –65°C to 150°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

package thermal data (see Note 1)

PACKAGE	BOARD	θ_{JC}	θ_{JA}
POWER-FLEX (KTP)	High K, JESD 51-5	19°C/W	28°C/W
SOT-223 (DCY)	High K, JESD 51-7	4°C/W	53°C/W
TO-220 (KC/KCS)	High K, JESD 51-5	3°C/W	19°C/W

NOTE 1: Maximum power dissipation is a function of T_J(max), θ_{JA}, and T_A. The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) – T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.

recommended operating conditions

			MIN	MAX	UNIT
V_I	Input voltage	μA78M33	5.3	25	V
		μA78M05	7	25	
		μA78M06	8	25	
		μA78M08	10.5	25	
		μA78M09	11.5	26	
		μA78M10	12.5	28	
		μA78M12	14.5	30	
		μA78M15	17.5	30	
I_O	Output current			500	mA
T_J	Operating virtual junction temperature		0	125	°C

The μA78M15 is obsolete and no longer is supplied.

electrical characteristics at specified virtual junction temperature, V_I = 8 V, I_O = 350 mA, T_J = 25°C (unless otherwise noted)

PARAMETER	TEST CONDITIONS†		μA78M33C MIN	μA78M33C TYP	μA78M33C MAX	UNIT
Output voltage‡	I_O = 5 mA to 350 mA, V_I = 8 V to 20 V		3.2	3.3	3.4	V
		T_J = 0°C to 125°C	3.1	3.3	3.5	
Input voltage regulation	I_O = 200 mA	V_I = 5.3 V to 25 V		9	100	mV
		V_I = 8 V to 25 V		3	50	
Ripple rejection	V_I = 8 V to 18 V, f = 120 Hz	I_O = 100 mA, T_J = 0°C to 125°C	62			dB
		I_O = 300 mA	62	80		
Output voltage regulation	V_I = 8 V,	I_O = 5 mA to 500 mA		20	100	mV
Temperature coefficient of output voltage	I_O = 5 mA,	T_J = 0°C to 125°C		–1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz			40	200	μV
Dropout voltage				2		V
Bias current				4.5	6	mA
Bias current change	I_O = 200 mA,	V_I = 8 V to 25 V, T_J = 0°C to 125°C			0.8	mA
	I_O = 5 mA to 350 mA,	T_J = 0°C to 125°C			0.5	
Short-circuit output current	V_I = 35 V			300		mA
Peak output current				700		mA

† All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.
‡ This specification applies only for dc power dissipation permitted by absolute maximum ratings.

electrical characteristics at specified virtual junction temperature, V_I = 10 V, I_O = 350 mA, T_J = 25°C (unless otherwise noted)

PARAMETER	TEST CONDITIONS†		μA78M05C MIN	μA78M05C TYP	μA78M05C MAX	UNIT
Output voltage	I_O = 5 mA to 350 mA, V_I = 7 V to 20 V		4.8	5	5.2	V
		T_J = 0°C to 125°C	4.75		5.25	
Input voltage regulation	I_O = 200 mA	V_I = 7 V to 25 V		3	100	mV
		V_I = 8 V to 25 V		1	50	
Ripple rejection	V_I = 8 V to 18 V, f = 120 Hz	I_O = 100 mA, T_J = 0°C to 125°C	62			dB
		I_O = 300 mA	62	80		
Output voltage regulation	I_O = 5 mA to 500 mA			20	100	mV
	I_O = 5 mA to 200 mA			10	50	
Temperature coefficient of output voltage	I_O = 5 mA,	T_J = 0°C to 125°C		–1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz			40	200	μV
Dropout voltage				2		V
Bias current				4.5	6	mA
Bias current change	I_O = 200 mA,	V_I = 8 V to 25 V, T_J = 0°C to 125°C			0.8	mA
	I_O = 5 mA to 350 mA,	T_J = 0°C to 125°C			0.5	
Short-circuit output current	V_I = 35 V			300		mA
Peak output current				0.7		A

† All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

The μA78M15 is obsolete and no longer is supplied.

electrical characteristics at specified virtual junction temperature, V_I = 11 V, I_O = 350 mA, T_J = 25°C (unless otherwise noted)

PARAMETER	TEST CONDITIONS†			μA78M06C MIN	μA78M06C TYP	μA78M06C MAX	UNIT
Output voltage	I_O = 5 mA to 350 mA,	V_I = 8 V to 21 V		5.75	6	6.25	V
			T_J = 0°C to 125°C	5.7		6.3	
Input voltage regulation	I_O = 200 mA	V_I = 8 V to 25 V			5	100	mV
		V_I = 9 V to 25 V			1.5	50	
Ripple rejection	V_I = 9 V to 19 V,	f = 120 Hz	I_O = 100 mA, T_J = 0°C to 125°C	59			dB
			I_O = 300 mA	59	80		
Output voltage regulation	I_O = 5 mA to 500 mA				20	120	mV
	I_O = 5 mA to 200 mA				10	60	
Temperature coefficient of output voltage	I_O = 5 mA,	T_J = 0°C to 125°C			–1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz				45		μV
Dropout voltage					2		V
Bias current					4.5	6	mA
Bias current change	V_I = 9 V to 25 V,	I_O = 200 mA,	T_J = 0°C to 125°C			0.8	mA
	I_O = 5 mA to 350 mA,	T_J = 0°C to 125°C				0.5	
Short-circuit output current	V_I = 35 V				270		mA
Peak output current					0.7		A

† All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

electrical characteristics at specified virtual junction temperature, V_I = 14 V, I_O = 350 mA, T_J = 25°C (unless otherwise noted)

PARAMETER	TEST CONDITIONS†			μA78M08C MIN	μA78M08C TYP	μA78M08C MAX	UNIT
Output voltage	V_I = 10.5 V to 23 V,	I_O = 5 mA to 350 mA		7.7	8	8.3	V
			T_J = 0°C to 125°C	7.6		8.4	
Input voltage regulation	I_O = 200 mA	V_I = 10.5 V to 25 V			6	100	mV
		V_I = 11 V to 25 V			2	50	
Ripple rejection	V_I = 11.5 V to 21.5 V, f = 120 Hz	I_O = 100 mA,	T_J = 0°C to 125°C	56			dB
		I_O = 300 mA		56	80		
Output voltage regulation	I_O = 5 mA to 500 mA				25	160	mV
	I_O = 5 mA to 200 mA				10	80	
Temperature coefficient of output voltage	I_O = 5 mA,	T_J = 0°C to 125°C			–1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz				52		μV
Dropout voltage					2		V
Bias current					4.6	6	mA
Bias current change	V_I = 10.5 V to 25 V,	I_O = 200 mA,	T_J = 0°C to 125°C			0.8	mA
	I_O = 5 mA to 350 mA,	T_J = 0°C to 125°C				0.5	
Short-circuit output current	V_I = 35 V				250		mA
Peak output current					0.7		A

† All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

electrical characteristics at specified virtual junction temperature, V_I = 16 V, I_O = 350 mA, T_J = 25°C (unless otherwise noted)

PARAMETER	TEST CONDITIONS†			μA78M09C MIN	μA78M09C TYP	μA78M09C MAX	UNIT
Output voltage	V_I = 11.5 V to 24 V,	I_O = 5 mA to 350 mA		8.6	9	9.4	V
			T_J = 0°C to 125°C	8.5		9.5	
Input voltage regulation	I_O = 200 mA	V_I = 11.5 V to 26 V			6	100	mV
		V_I = 12 V to 26 V			2	50	
Ripple rejection	V_I = 13 V to 23 V, f = 120 Hz	I_O = 100 mA,	T_J = 0°C to 125°C	56			dB
		I_O = 300 mA		56	80		
Output voltage regulation	I_O = 5 mA to 500 mA				25	180	mV
	I_O = 5 mA to 200 mA				10	90	
Temperature coefficient of output voltage	I_O = 5 mA,	T_J = 0°C to 125°C			–1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz				58		μV
Dropout voltage					2		V
Bias current					4.6	6	mA
Bias current change	V_I = 11.5 V to 26 V,	I_O = 200 mA,	T_J = 0°C to 125°C			0.8	mA
	I_O = 5 mA to 350 mA,	T_J = 0°C to 125°C				0.5	
Short-circuit output current	V_I = 35 V				250		mA
Peak output current					0.7		A

† All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

electrical characteristics at specified virtual junction temperature, V_I = 17 V, I_O = 350 mA, T_J = 25°C (unless otherwise noted)

PARAMETER	TEST CONDITIONS†			μA78M10C MIN	μA78M10C TYP	μA78M10C MAX	UNIT
Output voltage	V_I = 12.5 V to 25 V,	I_O = 5 mA to 350 mA		9.6	10	10.4	V
			T_J = 0°C to 125°C	9.5		10.5	
Input voltage regulation	I_O = 200 mA	V_I = 12.5 V to 28 V			7	100	mV
		V_I = 14 V to 28 V			2	50	
Ripple rejection	V_I = 15 V to 25 V, f = 120 Hz	I_O = 100 mA,	T_J = 0°C to 125°C	59			dB
		I_O = 300 mA		55	80		
Output voltage regulation	I_O = 5 mA to 500 mA				25	200	mV
	I_O = 5 mA to 200 mA				10	100	
Temperature coefficient of output voltage	I_O = 5 mA,	T_J = 0°C to 125°C			–1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz				64		μV
Dropout voltage					2		V
Bias current					4.7	6	mA
Bias current change	V_I = 12.5 V to 28 V,	I_O = 200 mA,	T_J = 0°C to 125°C			0.8	mA
	I_O = 5 mA to 350 mA,	T_J = 0°C to 125°C				0.5	
Short-circuit output current	V_I = 35 V				245		mA
Peak output current					0.7		A

† All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

The μA78M15 is obsolete and no longer is supplied.

electrical characteristics at specified virtual junction temperature, V_I = 19 V, I_O = 350 mA, T_J = 25°C (unless otherwise noted)

PARAMETER	TEST CONDITIONS†			μA78M12C MIN	μA78M12C TYP	μA78M12C MAX	UNIT
Output voltage	V_I = 14.5 V to 27 V,	I_O = 5 mA to 350 mA		11.5	12	12.5	V
			T_J = 0°C to 125°C	11.4		12.6	
Input voltage regulation	I_O = 200 mA	V_I = 14.5 V to 30 V			8	100	mV
		V_I = 16 V to 30 V			2	50	
Ripple rejection	V_I = 15 V to 25 V, f = 120 Hz	I_O = 100 mA,	T_J = 0°C to 125°C	55			dB
		I_O = 300 mA		55	80		
Output voltage regulation	I_O = 5 mA to 500 mA				25	240	mV
	I_O = 5 mA to 200 mA				10	120	
Temperature coefficient of output voltage	I_O = 5 mA				–1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz				75		μV
Dropout voltage					2		V
Bias current					4.8	6	mA
Bias current change	V_I = 14.5 V to 30 V,	I_O = 200 mA,	T_J = 0°C to 125°C			0.8	mA
	I_O = 5 mA to 350 mA,	T_J = 0°C to 125°C				0.5	
Short-circuit output current	V_I = 35 V				240		mA
Peak output current					0.7		A

† All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

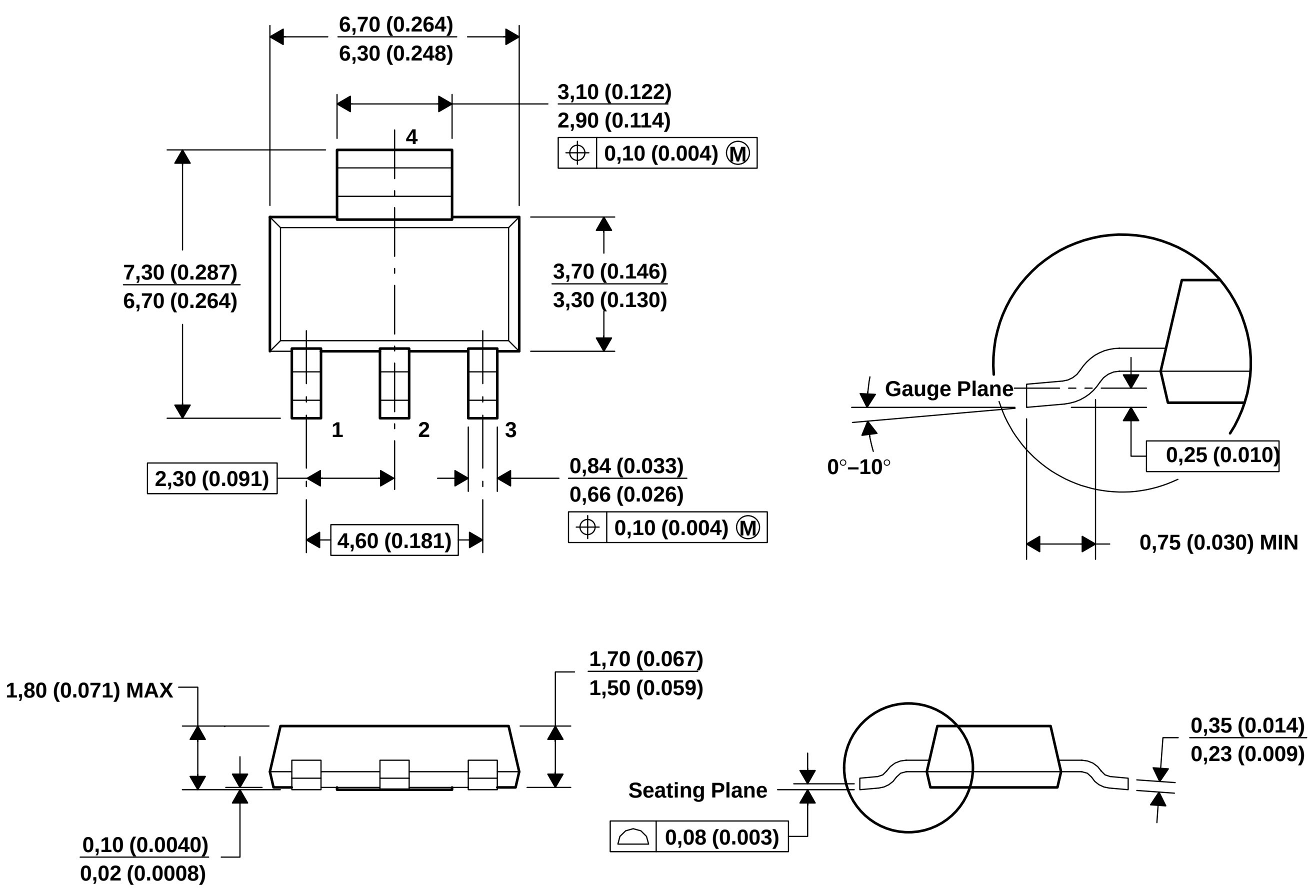
electrical characteristics at specified virtual junction temperature, V_I = 23 V, I_O = 350 mA, T_J = 25°C (unless otherwise noted)

PARAMETER	TEST CONDITIONS†			μA78M15C MIN	μA78M15C TYP	μA78M15C MAX	UNIT
Output voltage	V_I = 17.5 V to 30 V,	I_O = 5 mA to 350 mA		14.4	15	15.6	V
			T_J = 0°C to 125°C	14.25		15.75	
Input voltage regulation	I_O = 200 mA	V_I = 17.5 V to 30 V			10	100	mV
		V_I = 20 V to 30 V			3	50	
Ripple rejection	V_I = 18.5 V to 28.5 V, f = 120 Hz	I_O = 100 mA,	T_J = 0°C to 125°C	54			dB
		I_O = 300 mA		54	70		
Output voltage regulation	I_O = 5 mA to 500 mA				25	300	mV
	I_O = 5 mA to 200 mA				10	150	
Temperature coefficient of output voltage	I_O = 5 mA,	T_J = 0°C to 125°C			–1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz				90		μV
Dropout voltage					2		V
Bias current					4.8	6	mA
Bias current change	V_I = 17.5 V to 30 V,	I_O = 200 mA,	T_J = 0°C to 125°C			0.8	mA
	I_O = 5 mA to 350 mA,	T_J = 0°C to 125°C				0.5	
Short-circuit output current	V_I = 35 V				240		mA
Peak output current					0.7		A

OBSOLETE

† All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

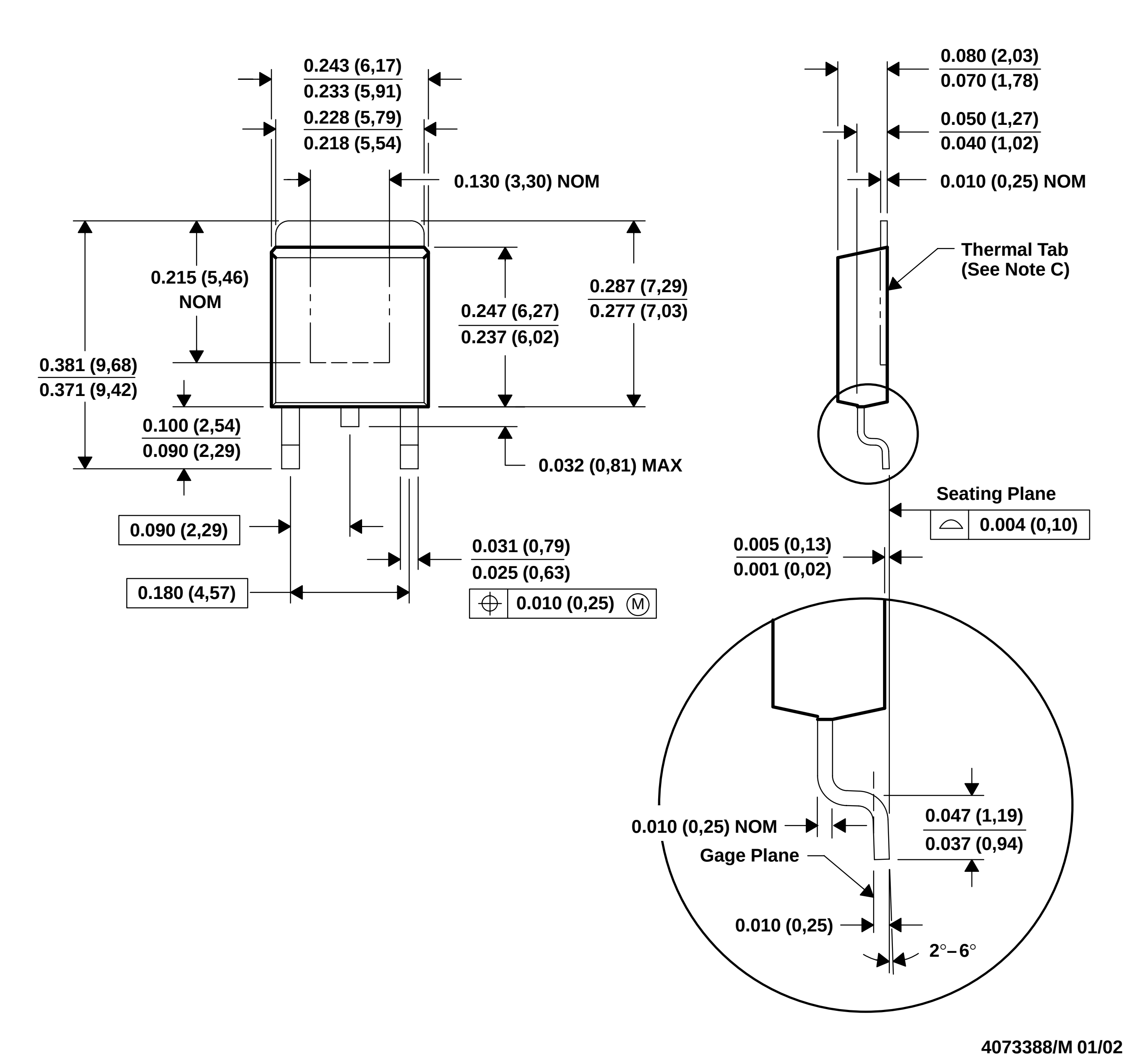
DCY (R-PDSO-G4) **PLASTIC SMALL-OUTLINE**



4202506/B 06/2002

NOTES:
- A. All linear dimensions are in millimeters (inches).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion.
- D. Falls within JEDEC TO-261 Variation AA.

KTP (R-PSFM-G2) **PowerFLEX™ PLASTIC FLANGE-MOUNT PACKAGE**



NOTES: A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. The center lead is in electrical contact with the thermal tab.
D. Dimensions do not include mold protrusions, not to exceed 0.006 (0,15).
E. Falls within JEDEC TO-252 variation AC.

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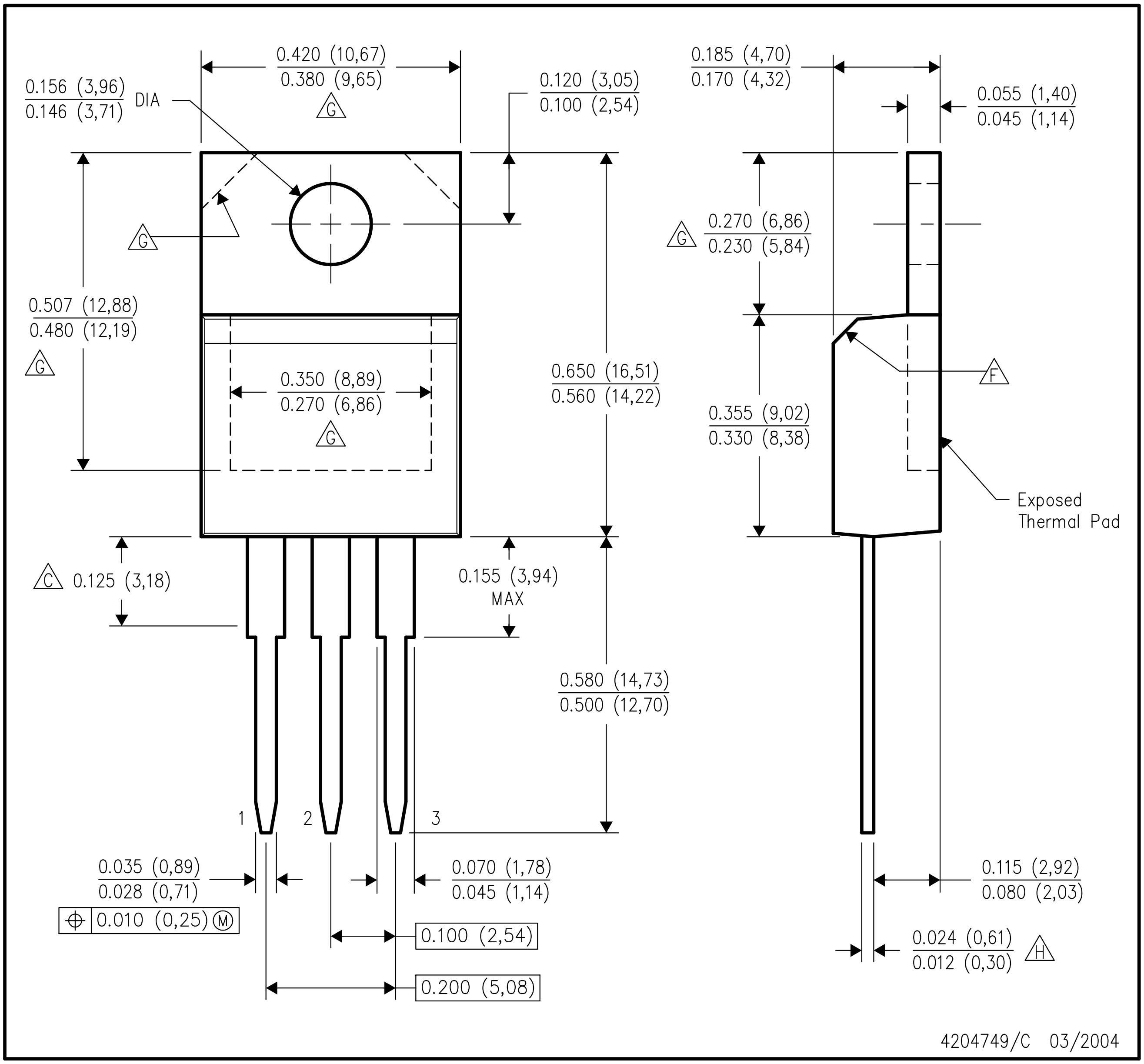
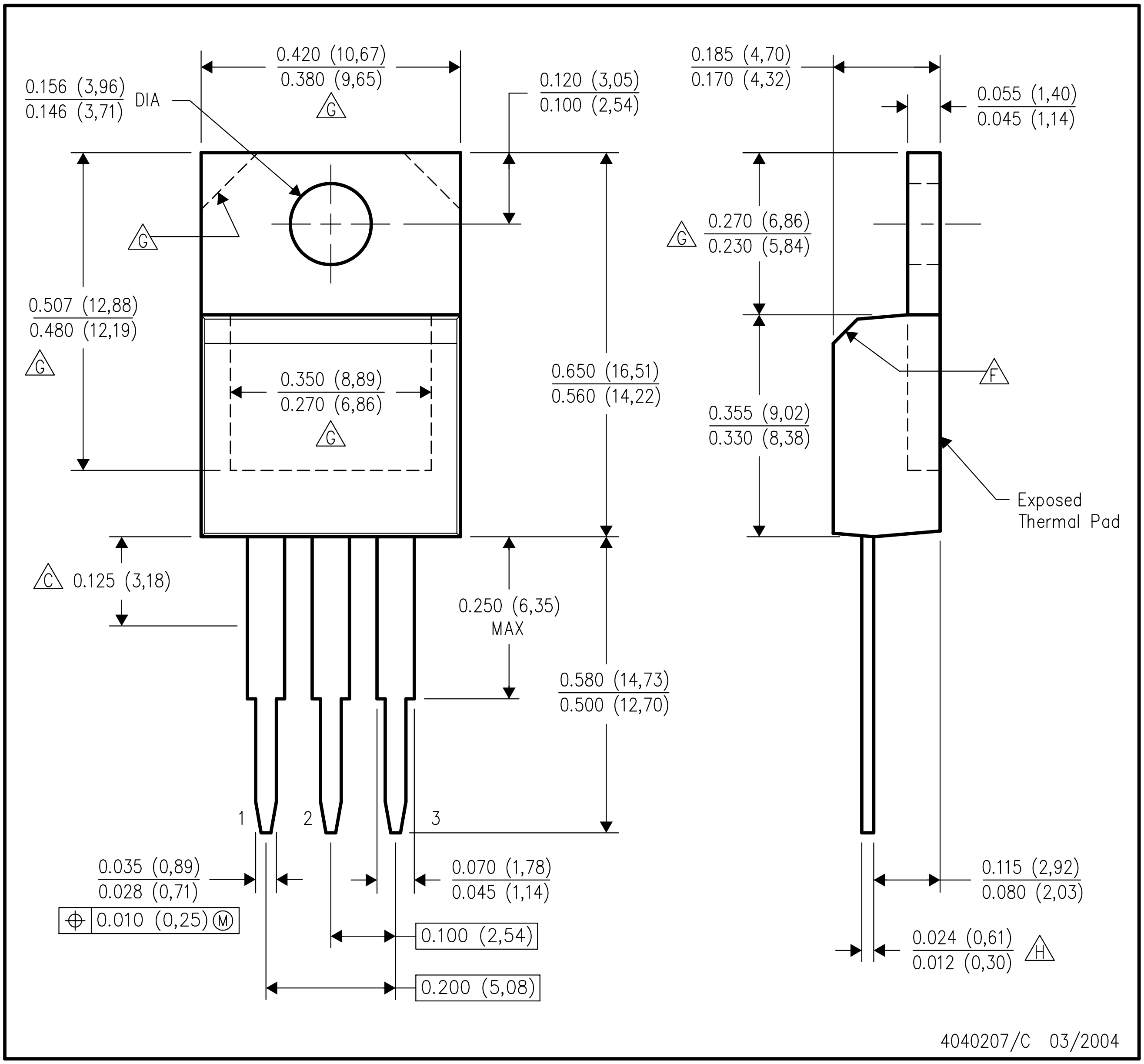
KCS (R–PSFM–T3) PLASTIC FLANGE–MOUNT PACKAGE



NOTES:

A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Lead dimensions are not controlled within this area.
D. All lead dimensions apply before solder dip.
E. The center lead is in electrical contact with the mounting tab.
F. The chamfer is optional.
G. Thermal pad contour optional within these dimensions.
H. Falls within JEDEC TO–220 variation AB, except minimum lead thickness.

KC (R–PSFM–T3) PLASTIC FLANGE–MOUNT PACKAGE



NOTES:
- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Lead dimensions are not controlled within this area.
- D. All lead dimensions apply before solder dip.
- E. The center lead is in electrical contact with the mounting tab.
- F. The chamfer is optional.
- G. Thermal pad contour optional within these dimensions.
- H. Falls within JEDEC TO–220 variation AB, except minimum lead thickness.

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